



Docket No.: R2184.0282/P282
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Hirokazu Iwata et al.

Application No.: 10/765,502

Confirmation No.: 2556

Filed: January 28, 2004

Art Unit: 1722

For: METHODS OF GROWING A GROUP III
NITRIDE CRYSTAL (AS AMENDED)

Examiner: R. Kunemund

AMENDMENT IN RESPONSE TO NON-FINAL OFFICE ACTION

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action dated August 22, 2006, please amend the above-identified U.S. patent application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks/Arguments begin on page 13 of this paper.